








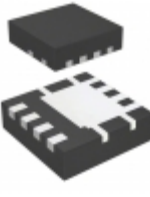



|   |                                |   |
|---|--------------------------------|---|
|   | <b>DMT10H015LSS-13</b>         |   |
|   | <b>Hersteller-Teilenummer:</b> | DMT10H015LSS-13   |
|  | <b>Hersteller / Marke:</b>     | Diodes Incorporated   |
|   | <b>Teil der Beschreibung:</b>  | MOSFET N-CH 100V 8.3A   |
|   | <b>Datenblätter:</b>           |  <a href="#">DMT10H015LSS-13.pdf</a> |
|   | <b>RoHs Status:</b>            | Bleifrei / RoHS-konform   |
|   | <b>Lagerzustand:</b>           | New original, 15075 pcs Stock Available.  |
|   | <b>Liefern von:</b>            | Hong Kong   |
|   | <b>Versandweg:</b>             | DHL/Fedex/TNT/UPS/EMS   |
| Image may be representation. See specs for product details.                       |                                |   |

### Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | DMT10H015LSS-13   |
| Hersteller                                       | Diodes Incorporated   |
| Beschreibung                                     | MOSFET N-CH 100V 8.3A   |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> , |
| Teilstatus                                       | 15075 pcs Stock   |
| Serie  | -   |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Surface Mount   |
| Verpackung / Gehäuse                             | 8-SOIC (0.154", 3.90mm Width)   |
| Supplier Device-Gehäuse                          | 8-SO  |
| Verlustleistung (max)                            | 1.2W (Ta)   |
| Typ FET  | N-Channel   |
| FET-Merkmal                                      | -   |
| Drain-Source-Spannung (Vdss)                     | 100V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 8.3A (Ta)   |
| Rds On (Max) @ Id, Vgs                           | 16 mOhm @ 20A, 10V  |
| VGS (th) (Max) @ Id                              | 3.5V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                     | 33.3nC @ 10V  |
| Eingabekapazität (Ciss) (Max) @ Vds              | 1871pF @ 50V  |
| Antriebsspannung (Max Rds On, Min Rds On)        | 4.5V, 10V   |
| Vgs (Max)  | ±20V  |
| Verpackung                                       | Tape & Reel (TR)  |



















































DMT10H015LSS-13 ist neu im Original, Suche DMT10H015LSS-13 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMT10H015LSS-13 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMT10H015LSS-13: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|  |   |  |  |
|--|---|--|--|
| <br><b>DMT10H025SSS</b><br>Diodes Incorporated<br>DMT10H025SSS DIODES     | <br><b>DMT10H015LSS</b><br>Diodes Incorporated<br>DMT10H015LSS DIODES                | <br><b>DMT10H015LFG-7</b><br>Diodes Incorporated<br>MOSFET N-CH 100V 10A               | <br><b>DMT10H025SSS-13</b><br>Diodes Incorporated<br>MOSFETN-CHAN 100V SO-8           |
| <br><b>DMT10H015LFG-13</b><br>Diodes Incorporated<br>MOSFET N-CH 100V 10A | <br><b>DMT1D1K</b><br>Cornell Dubilier Electronics<br>CAP FILM 1000PF 10% 100VDC RAD | <br><b>DMT1D1K-F</b><br>Cornell Dubilier Electronics<br>CAP FILM 1000PF 10% 100VDC RAD | <br><b>DMT10H015LK3-13</b><br>Diodes Incorporated<br>MOSFET BVDSS: 61V 100V TO252 T&R |

### heiße Teile

Mehr

|   |   |   |  |   |
|---|---|---|--|---|
|  DMT10H010LSS  |  DMT10H014LSS  |  DMT10H015LK3-13 |  DMT10H015LSS   |  DMT10H025SSS  |
|  DMT3001LPS    |  DMT3002LPS-13 |  DMT3003LFG-13   |  DMT3003LFG-7   |  DMT3004LFG-13 |
|  DMT3004LPS-13 |  DMT3006LFG-13 |  DMT3006LFV      |  DMT3006LPS-13  |  DMT3009LDT    |
|  DMT3009LDT-13 |  DMT3009LDT-7  |  DMT3009LFVW     |  DMT3009LFVW-13 |  DMT3009LFVW-7 |
|  DMT3020LPS    |  DMT3020LSD    |  DMT32M5LPS      |  DMT4011LFG-7   |  DMT40M9LPS-13 |
|  DMT6004LPS-13 |  DMT6004SPS    |  DMT6004SPS-13   |  DMT6005LPS     |  DMT6005LPS-13 |
|  DMT6005LSS    |  DMT6008LFG    |  DMT6008LFG-7    |  DMT6009LCT     |  DMT6009LFG    |
|  DMT6009LFG-13 |  DMT6009LK3    |  DMT6009LPS      |  DMT6009LPS-13  |  DMT6009LSS    |
|  DMT6010LFG    |  DMT6010LFG-13 |  DMT6010LFG-7    |  DMT6010LPS-13  |  DMT6010LSS    |
|  DMT6010LSS-13 |  DMT6010SCT    |  DMT6015LFV      |  DMT6015LFV-13  |  DMT6015LFV-7  |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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